

Excellent Integrated System Limited

Stocking Distributor

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[Powerex Inc.](#)
[CM75TU-12H](#)

For any questions, you can email us directly:

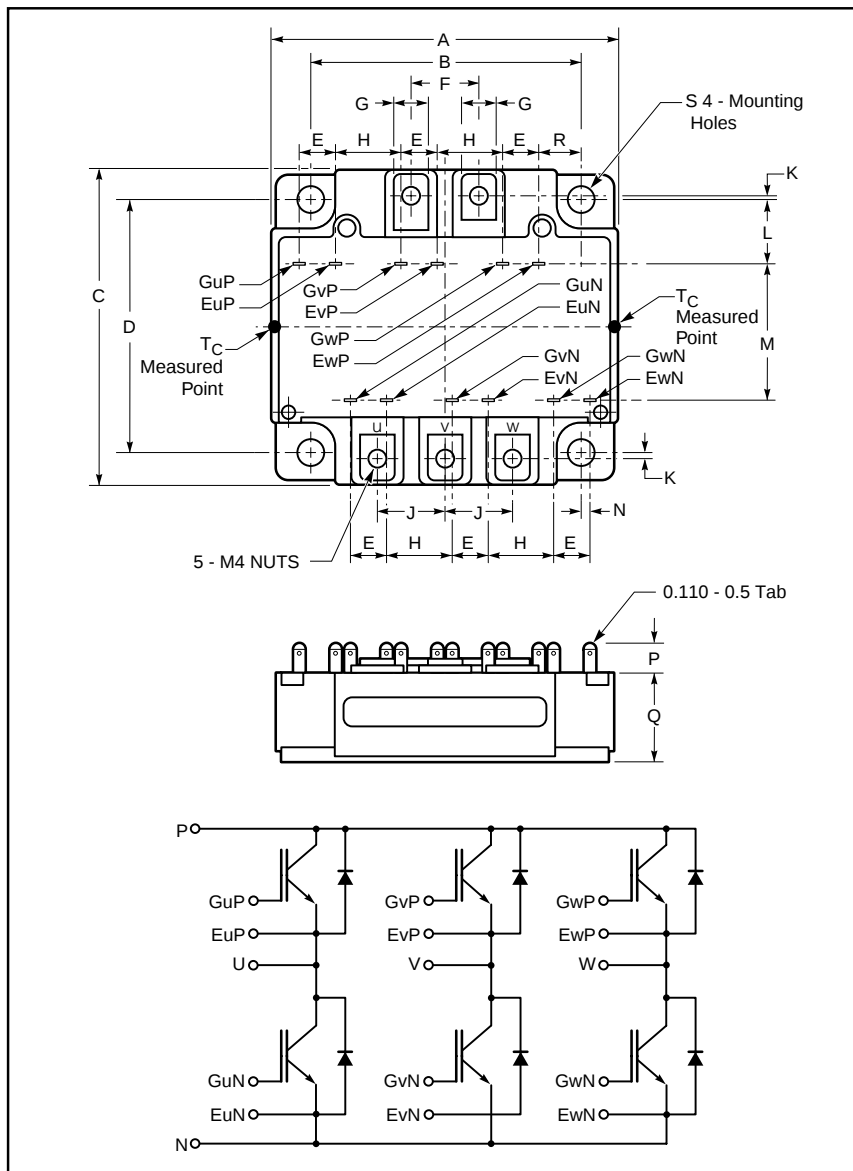
sales@integrated-circuit.com



Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

CM75TU-12H

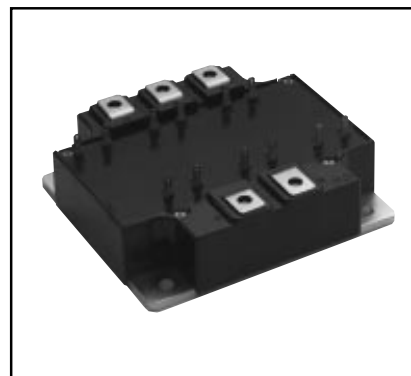
Six IGBTMOD™ U-Series Module 75 Amperes/600 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	4.02	102.0
B	3.15±0.01	80.0±0.25
C	3.58	91.0
D	2.91±0.01	74.0±0.25
E	0.43	11.0
F	0.79	20.0
G	0.39	10.0
H	0.75	19.1
J	0.79	20.0

Dimensions	Inches	Millimeters
K	0.05	1.25
L	0.74	18.7
M	1.55	39.3
N	0.12	3.05
P	0.32	8.1
Q	1.02	26.0
R	0.47	11.85
S	0.22 Dia.	5.5 Dia.



Description:

Powerex IGBTMOD™ Modules are designed for use in switching applications. Each module consists of six IGBT Transistors in a three phase bridge configuration, with each transistor having a reverse-connected super-fast recovery free-wheel diode. All components and interconnects are isolated from the heat sinking baseplate, offering simplified system assembly and thermal management.

Features:

- ☐ Low Drive Power
- ☐ Low $V_{CE(sat)}$
- ☐ Discrete Super-Fast Recovery Free-Wheel Diode
- ☐ Isolated Baseplate for Easy Heat Sinking

Applications:

- ☐ AC Motor Control
- ☐ Motion/Servo Control
- ☐ UPS
- ☐ Welding Power Supplies
- ☐ Laser Power Supplies

Ordering Information:

Example: Select the complete module number you desire from the table - i.e. CM75TU-12H is a 600V (V_{CES}), 75 Ampere Six-IGBT IGBTMOD™ Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 50)
CM	75	12



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CM75TU-12H

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75 Amperes/600 Volts

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	CM75TU-12H	Units
Junction Temperature	T_j	-40 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Collector-Emitter Voltage (G-E SHORT)	V_{CES}	600	Volts
Gate-Emitter Voltage (C-E SHORT)	V_{GES}	± 20	Volts
Collector Current ($T_c = 25^\circ\text{C}$)	I_C	75	Amperes
Peak Collector Current ($T_j \leq 150^\circ\text{C}$)	I_{CM}	150*	Amperes
Emitter Current**	I_E	75	Amperes
Peak Emitter Current**	I_{EM}	150*	Amperes
Maximum Collector Dissipation ($T_j < 150^\circ\text{C}$)	P_c	310	Watts
Mounting Torque, M4 Main Terminal	—	15	in-lb
Mounting Torque, M5 Mounting	—	31	in-lb
Weight	—	570	Grams
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{iso}	2500	Volts

* Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed $T_{j(\text{max})}$ rating.

**Represents characteristics of the anti-parallel, emitter-to-collector free-wheel diode (FWDI).

Static Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Collector-Cutoff Current	I_{CES}	$V_{\text{CE}} = V_{\text{CES}}, V_{\text{GE}} = 0\text{V}$	—	—	1	mA
Gate Leakage Voltage	I_{GES}	$V_{\text{GE}} = V_{\text{GES}}, V_{\text{CE}} = 0\text{V}$	—	—	0.5	μA
Gate-Emitter Threshold Voltage	$V_{\text{GE(th)}}$	$I_C = 7.5\text{mA}, V_{\text{CE}} = 10\text{V}$	4.5	6	7.5	Volts
Collector-Emitter Saturation Voltage	$V_{\text{CE(sat)}}$	$I_C = 75\text{A}, V_{\text{GE}} = 15\text{V}, T_j = 25^\circ\text{C}$	—	2.4	3.0	Volts
		$I_C = 75\text{A}, V_{\text{GE}} = 15\text{V}, T_j = 125^\circ\text{C}$	—	2.6	—	Volts
Total Gate Charge	Q_G	$V_{\text{CC}} = 300\text{V}, I_C = 75\text{A}, V_{\text{GE}} = 15\text{V}$	—	150	—	nC
Emitter-Collector Voltage*	V_{EC}	$I_E = 75\text{A}, V_{\text{GE}} = 0\text{V}$	—	—	2.6	Volts

* Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed $T_{j(\text{max})}$ rating.

Dynamic Electrical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics		Symbol	Test Conditions	Min.	Typ.	Max.	Units
Input Capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0V	—	—	6.6	nf
Output Capacitance		C _{oes}		—	—	3.6	nf
Reverse Transfer Capacitance		C _{res}		—	—	1	nf
Resistive	Turn-on Delay Time	t _{d(on)}	V _{CC} = 300V, I _C = 75A,	—	—	100	ns
Load	Rise Time	t _r	V _{GE1} = V _{GE2} = 15V,	—	—	250	ns
Switch	Turn-off Delay Time	t _{d(off)}	R _G = 8.3Ω, Resistive	—	—	200	ns
Times	Fall Time	t _f	Load Switching Operation	—	—	300	ns
Diode Reverse Recovery Time		t _{rr}	I _E = 75A, di _E /dt = -150A/μs	—	—	160	ns
Diode Reverse Recovery Charge		Q _{rr}	I _E = 75A, di _E /dt = -150A/μs	—	0.18	—	μC

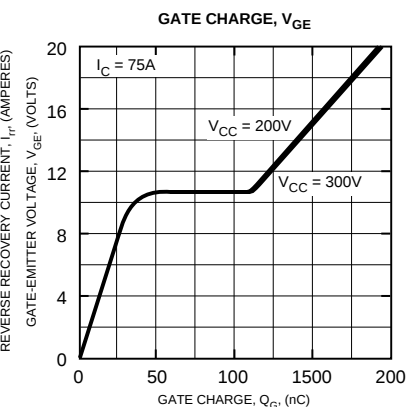
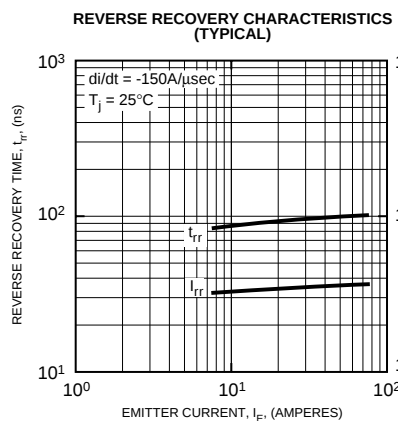
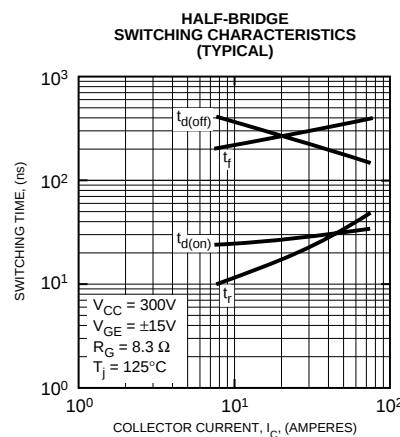
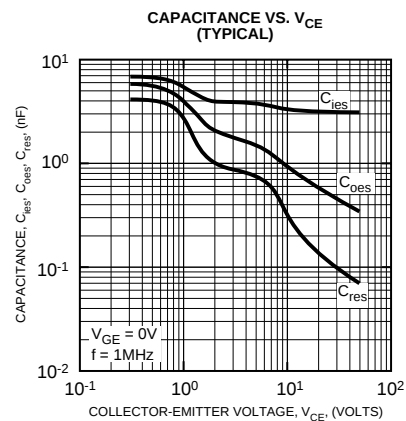
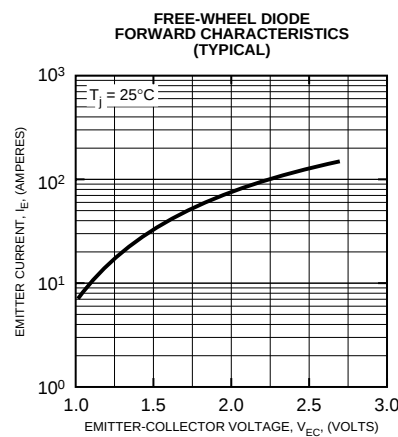
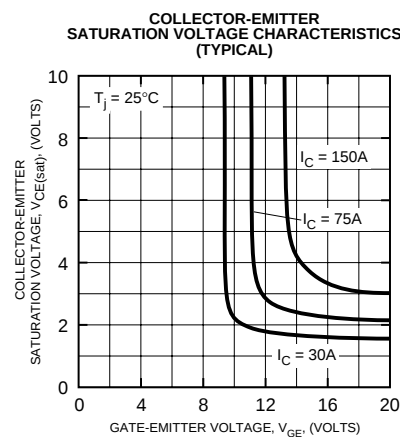
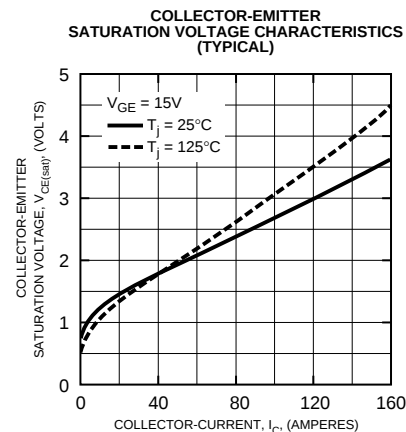
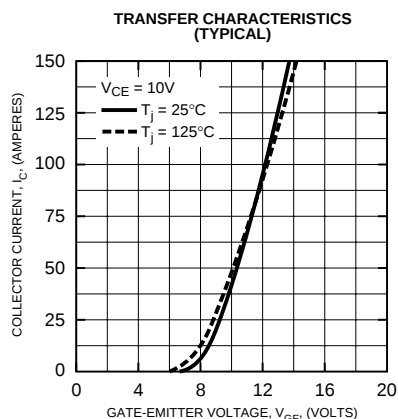
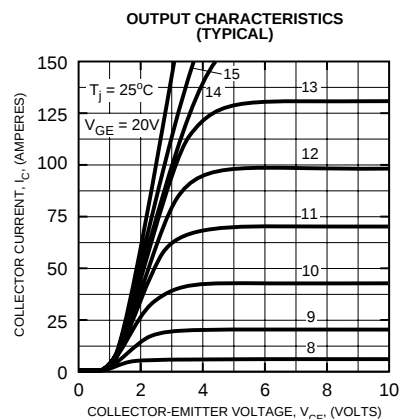
Thermal and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Thermal Resistance, Junction to Case	$R_{\text{th(j-c)Q}}$	Per IGBT 1/6 Module	—	—	0.4	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\text{th(j-c)D}}$	Per Free-Wheel Diode 1/6 Module	—	—	0.9	$^\circ\text{C}/\text{W}$
Contact Thermal Resistance	$R_{\text{th(c-f)}}$	Per Module, Thermal Grease Applied	—	0.018	—	$^\circ\text{C}/\text{W}$



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